Physics of Electronics:

4. Conduction in Metals

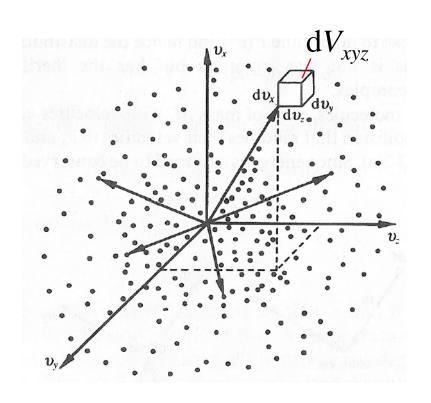
July – December 2008

Contents overview

- Assemblies of classical particles.
- Collection of particles obeying the exclusion principle.
- A simple model of a conductor.
- Electrons in a 3D box.
- Maximum number of possible energy states.
- Energy distribution of electrons in a metal.
- Fermi level in a metal.
- Conduction processes in metals.

Assemblies of Classical Particles

Consider a gas of N neutral molecules



The number of particles in dV_{xyz} is

$$dN_{xyz} = P(v^2) dv_x dv_y dv_z$$

and in a shell of thickness dv is

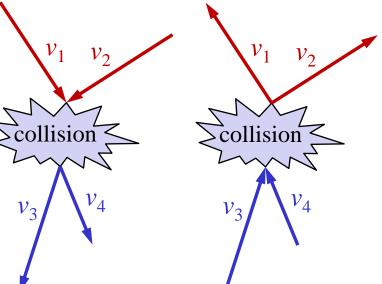
$$dN_v = P(v^2) 4\pi v^2 dv$$

where $P(v^2)$ is the density of particles having a speed v (i.e. density of points in *v*-space).

Total number of particles is:
$$\int_0^\infty dN_v = \int_0^\infty P(v^2) 4\pi v^2 dv = N$$

Assemblies of Classical Particles

- The distribution function (distribution of speeds):
 - To find $P(v^2)$ let's consider collisions inside this gas



Collision and reversed collision:

$$P(v_1^2)P(v_2^2) = P(v_3^2)P(v_4^2)$$

Energy conservation:

$$v_1^2 + v_2^2 = v_3^2 + v_4^2$$

$$P(v^2) = A \exp(-\beta v^2)$$

– Constants A and β are found from:

Total number of particles:
$$N = 4\pi A \int_0^\infty \exp(-\beta v^2)v^2 dv$$
Definition of T :
$$\int_0^\infty \frac{1}{2}(M v^2) \left[A \exp(-\beta v^2)\right] 4\pi v^2 dv = \frac{3}{2}NkT$$

$$A = N\left(\frac{M}{2\pi kT}\right)^{3/2}$$

Mean kinetic energy

Maxwell-Boltzmann Distribution Function

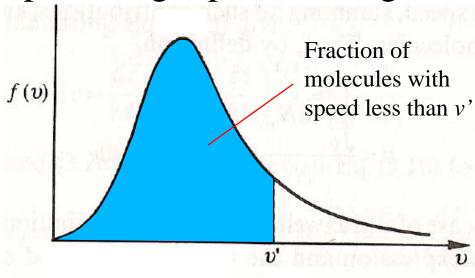
- Relation between $P(v^2)$ and f(v):
 - Number of particles in a shell of thickness dv:

$$dN_v = P(v^2)4\pi v^2 dv$$

$$dN_v = Nf(v) dv$$

$$f(v) = 4\pi \left(\frac{M}{2\pi kT}\right)^{3/2} \exp\left(-\frac{Mv^2}{2kT}\right)v^2$$

-f(v) gives the fraction of molecules (per unit volume) in a given speed range (per unit range of speed).



Energy Distribution Function

- From speed to energy distribution:
 - Considering only kinetic energy:

kT

 $E_{\rm p} = kT/2$

$$E = \frac{Mv^2}{2} \qquad \Longrightarrow \qquad dv = \frac{dE}{Mv} = \frac{dE}{M} \left(\frac{M}{2E}\right)^{1/2} = \frac{dE}{(2EM)^{1/2}}$$

- Replacing on dN_{ν} :

$$dN_v = Nf(v) dv = N \cdot 4\pi \left(\frac{M}{2\pi kT}\right)^{3/2} \exp\left(-\frac{Mv^2}{dv}\right)v^2$$

$$= N\left(4\pi \left(\frac{M}{2\pi kT}\right)^{3/2} \exp\left(-\frac{E}{kT}\right)\frac{2E}{M}\frac{dE}{(2EM)^{1/2}} = dN_E$$
Note that the density of the particle of the resistion

Note that the density of the particles is independent of the position

Boltzmann Distribution Function

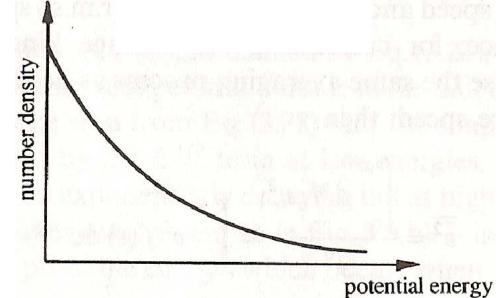
- How the energy is distributed in the ensemble
 - We now consider that the particles in the ensemble not only have KE but also PE (gravitational or electrical field).

$$f(E) \propto \exp(-E/kT) \propto \exp[-(KE + PE)/kT]$$

If the PE depends on the position so does the density of

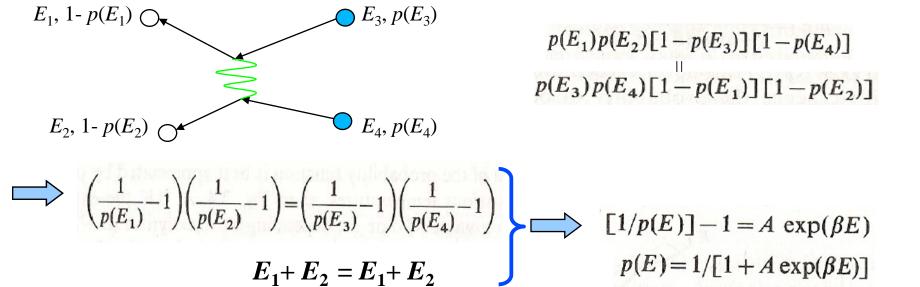
the ensemble:

$$n_2/n_1 = \exp[-e(V_2 - V_1)/kT]$$



Fermi-Dirac Distribution

- Ensembles obeying exclusion principle
 - Two quantum particles (E_3, E_4) interact and end up in two states (E_1, E_2) previously empty:



- When $E \rightarrow \infty$ it reduces to the Boltzmann distribution:

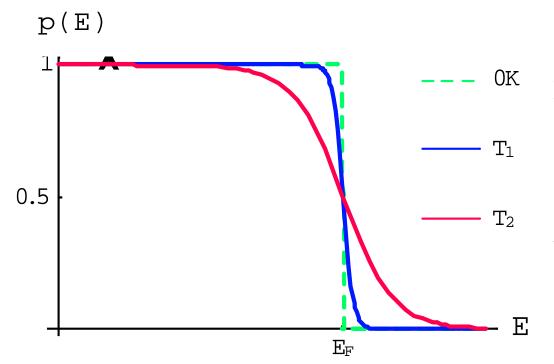
$$p(E) \simeq A \exp(-\beta E) \implies \beta = 1/kT$$

Fermi-Dirac Distribution

- Ensembles obeying exclusion principle
 - The constant A is redefined through E_F and can be found via normalization

$$A = \exp(-E_F/kT)$$

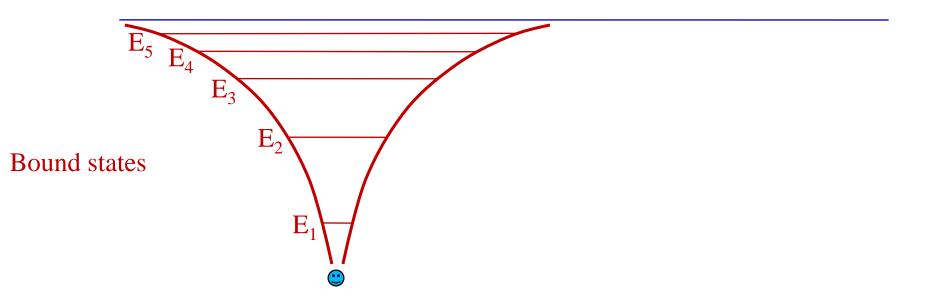
$$p(E) = \frac{1}{1 + \exp[(E - E_F)/kT]}$$



Note that for T = 0, p(E) reduces to a step function. It means that all the states with energies $E \le E_F$ are occupied and those above, are empty. When T > 0, some states below E_F are emptied and some are occupied due to thermal energy.

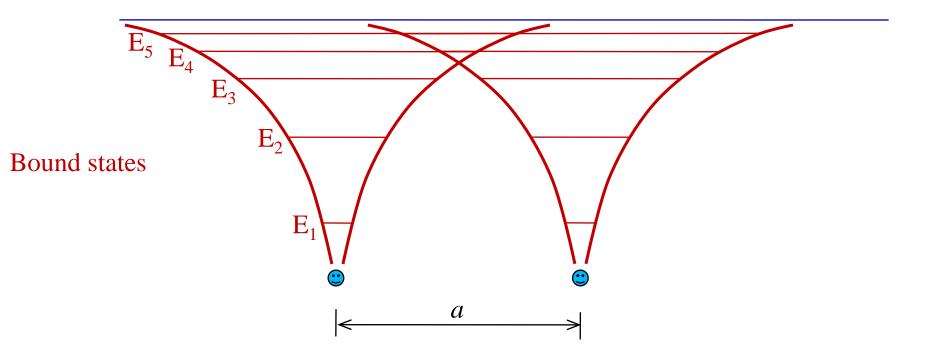
• From one atom to a collection of atoms:

Unbound states

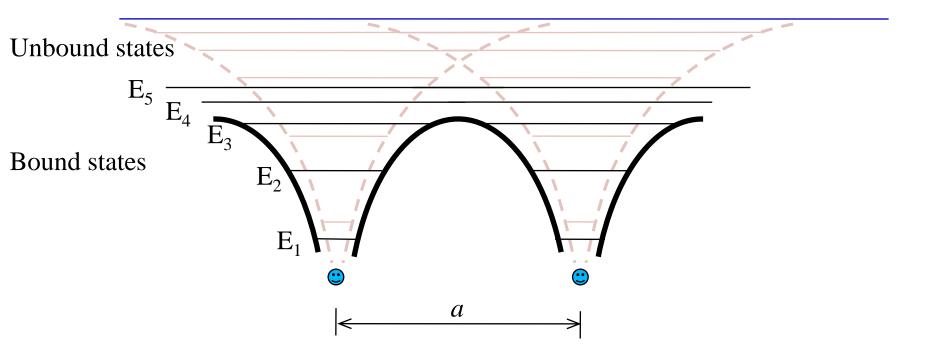


• From one atom to a collection of atoms:

Unbound states



• From one atom to a collection of atoms:



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~unperturbed potential

The potential barrier confines the electrons inside the faces of the conductor. Therefore we can model a conductor as unbound or free electrons confined to a potential box.

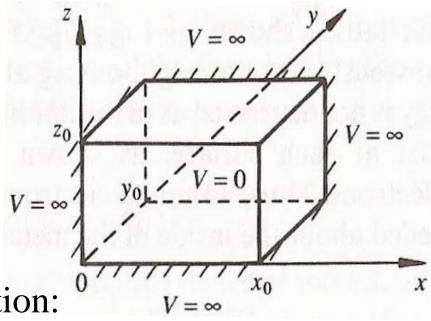
Electrons in a 3D box

- Free electron model: V = 0 inside box & $V = \infty$ outside box
 - Start from t-independent SE:

$$\nabla^2 \Psi + \frac{2m}{\hbar^2} (E - V) \Psi = 0$$



$$\frac{\partial^2 \Psi}{\partial x^2} + \frac{\partial^2 \Psi}{\partial y^2} + \frac{\partial^2 \Psi}{\partial z^2} + \frac{2m}{\hbar^2} E \Psi = 0$$



– Solving by variable separation:

$$\Psi = f_x(x) f_y(y) f_z(z)$$

$$\Psi = f_x(x) f_y(y) f_z(z) \qquad \frac{1}{f_x} \frac{d^2 f_x}{dx^2} + \frac{1}{f_y} \frac{d^2 f_y}{dy^2} + \frac{1}{f_z} \frac{d^2 f_z}{dz^2} = -\frac{2mE}{\hbar^2}$$



$$\frac{\mathrm{d}^2 f_x}{\mathrm{d} x^2} = C_1^2 f_x \quad \text{idem for } y \& z$$

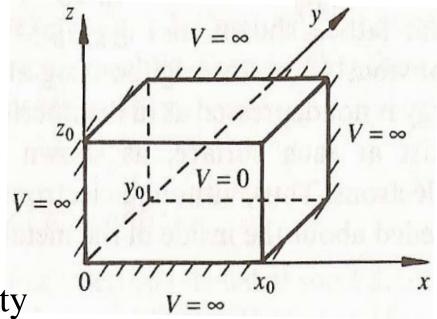
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 Solving and using continuity $(\Psi = 0 \text{ at the walls})$

$$f_x = A \sin(n_x \pi x/x_0)$$
 $f_y = B \sin(n_y \pi y/y_0)$

where n_x , n_y , $n_z = 1,2,3...$

$$f_z = C \sin(n_z \pi z/z_0)$$

Electrons in a 3D box

- Free electron model: V = 0 inside box & $V = \infty$ outside box
 - After normalization

$$\Psi_{n_x n_y n_z} = \left(\frac{2}{x_0}\right)^{1/2} \sin\left(\frac{n_x \pi x}{x_0}\right) \left(\frac{2}{y_0}\right)^{1/2} \sin\left(\frac{n_y \pi y}{y_0}\right) \left(\frac{2}{z_0}\right)^{1/2} \sin\left(\frac{n_z \pi z}{z_0}\right)$$

For every triplet (n_x, n_y, n_z) there exists an allowed state.

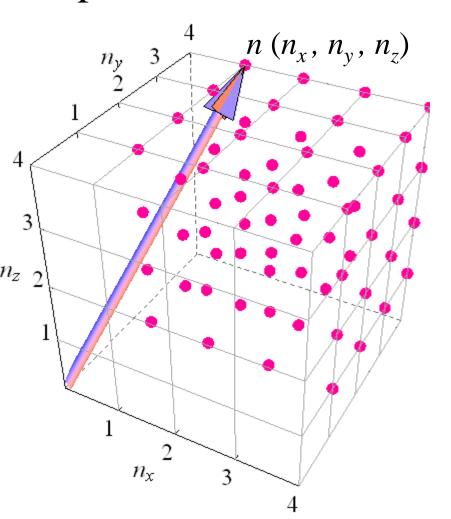
- Back into SE we obtain the energy of every state

$$E = \frac{h^2}{8md^2} n^2$$
 where
$$d = x_o = y_o = z_o$$
$$n^2 = n_x^2 + n_y^2 + n_z^2$$

Note that results are similar to 1D well

Space of States

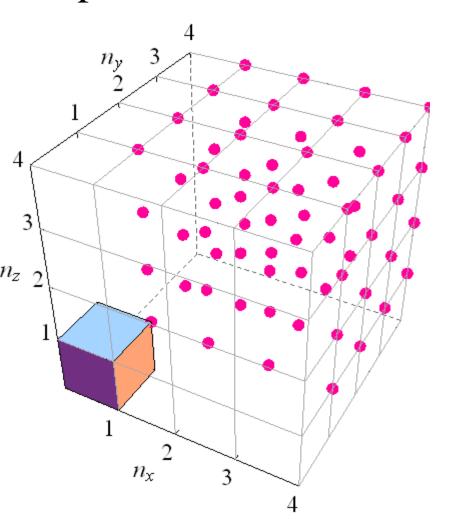
• We can represent every state as a point in a 3D space.



• In this representation, each point corresponds to one available state.

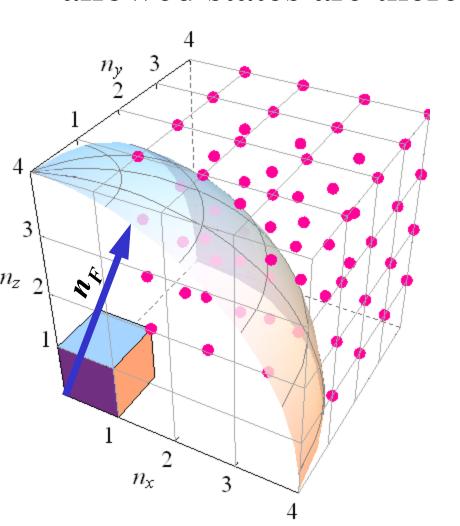
Space of States

• We can represent every state as a point in a 3D space.



- In this representation, each point corresponds to one available state.
- To each unit of volume corresponds one available state.
- We will consider large number of points (continuum limit).

• Given a (maximum) number n_F , how many allowed states are there?

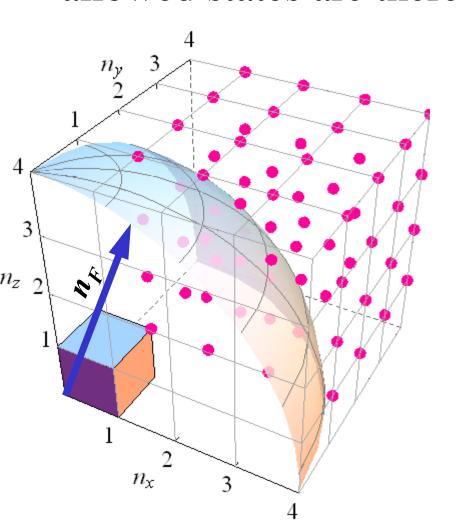


• How many triplets (n_x, n_y, n_z) are there such that:

$$n_F \ge n = (n_x^2 + n_y^2 + n_z^2)^{1/2}$$
?

• The loccus of n_F is a sphere.

• Given a (maximum) number n_F , how many allowed states are there?



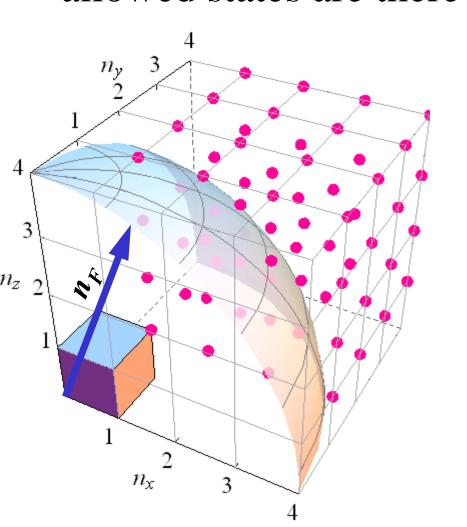
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$$n_F \ge n = (n_x^2 + n_y^2 + n_z^2)^{1/2}$$
?

- The loccus of n_F is a sphere.
- The number of states such that $n \le n_F$ corresponds to the volume generated by n_F :

$$V_F = \frac{1}{8} \left(\frac{4}{3} \pi n_F^3 \right) = \pi n_F^3 / 6$$

• Given a (maximum) number n_F , how many allowed states are there?



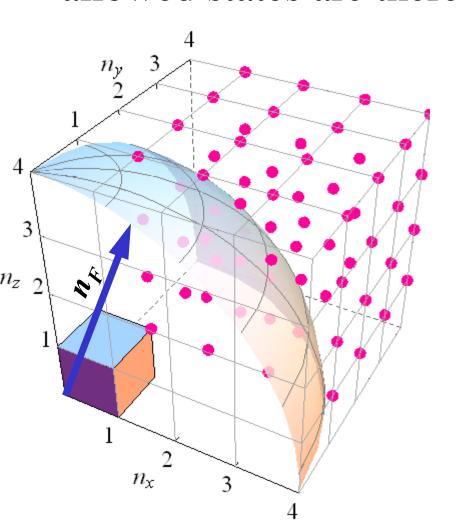
• How many triplets (n_x, n_y, n_z) are there such that:

$$n_F \ge n = (n_x^2 + n_y^2 + n_z^2)^{1/2}$$
?

- The loccus of n_F is a sphere.
- The number of states such that $n \le n_F$ corresponds to the volume generated by n_F (spin):

$$V_F = 2\pi n_F^3 / 6$$

• Given a (maximum) number n_F , how many allowed states are there?



• At 0 K we have:

Number of electrons = Number states $n \le n_F$

$$Nd^3 = \pi n_F^3/3$$

• Therefore:

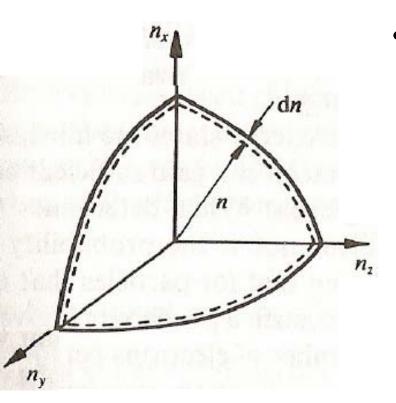
$$n_{\rm F} = (3N/\pi)^{1/3} d$$

• The energy corresponding to n_F :

$$E_{\rm F0} = \frac{h^2}{8m} \left(\frac{3N}{\pi}\right)^{2/3}$$

Energy Distribution of e- in a Metal

• What is the number of (available) states with energies in the range E and E+dE?

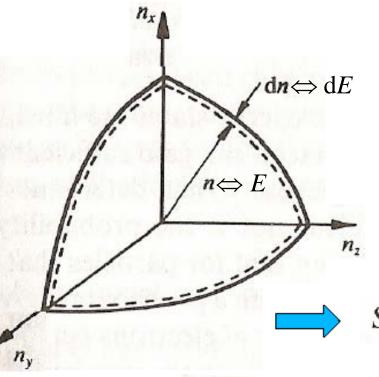


• Number of states in shell dn is equal to twice its volume:

$$2(4\pi n^2 dn)/8 = \pi n^2 dn$$

Energy Distribution of e- in a Metal

• What is the number of (available) states with energies in the range E and E+dE?



• Number of states in shell dn is equal to twice its volume:

$$2(4\pi n^2 dn)/8 = \pi n^2 dn$$

• Density of (available) states, S(E): S(E)dE gives the number of states with energies in the range *E* and *E*+d*E*

$$S(E) dE d^3 = \pi n^2 dn$$

$$S(E) = \frac{\pi n^2}{d^3} \frac{dn}{dE}$$

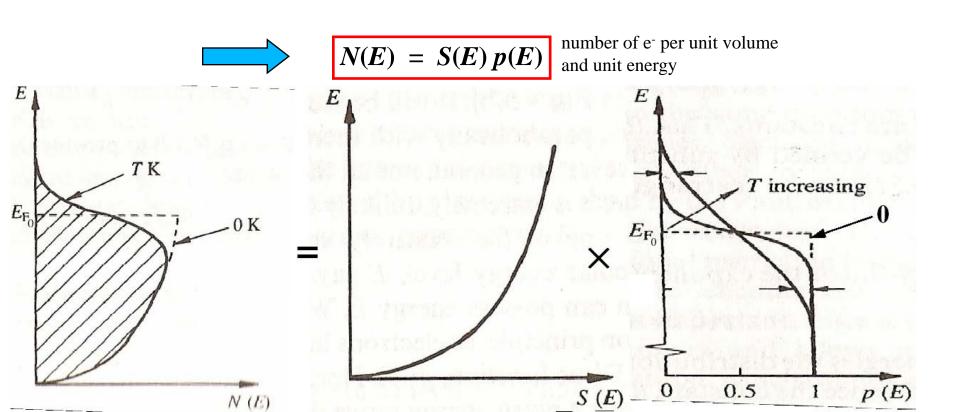
$$E = \frac{h^2}{8md^2} n^2$$

$$S(E) = \frac{(8\sqrt{2})\pi m^{3/2}}{h^3} E^{1/2}$$

Energy Distribution of e- in a Metal

• What is the number of (available) states with energies in the range E and E+dE?

$$N(E)dE = S(E)dE \times p(E)$$
number of e⁻ = number of available states × probability of occupation



Fermi Level in a Metal

• From N(E) the number of electrons in a metal is:

$$n = \int_0^\infty N(E) dE = \int_0^\infty S(E) p(E) dE = \frac{(8\sqrt{2})\pi m^{3/2}}{h^3} \int_0^\infty \frac{E^{1/2} dE}{1 + \exp[(E - E_F)/kT]}$$

• At T = 0:

$$n = \frac{(8\sqrt{2})\pi m^{3/2}}{h^3} \int_0^{E_{\text{FO}}} E^{1/2} dE \qquad \Longrightarrow \qquad E_{\text{FO}} = \frac{h^2}{8m} \left(\frac{3n}{\pi}\right)^{2/3} = 3.65 \times 10^{-19} n^{2/3} \text{ eV}$$

- Note that in a gas the energy of the particles is 0.
- In a metal the electrons have an energy up to E_{F0} (few eV's).
- At T > 0: $E_{\rm F} \approx E_{\rm F0} \left[1 \frac{\pi^2}{12} \left(\frac{kT}{E_{\rm F0}} \right)^2 \right]$

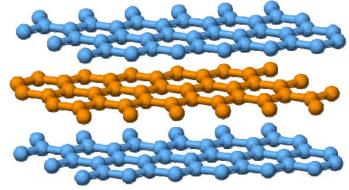
• At usual temperatures kT ~ meV
$$E_F$$
 depends slowly on T .

Conclusions

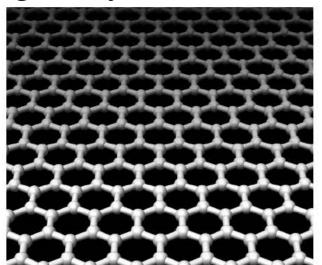
- We have introduced a simple model for electrons in a solid: free electron model.
- We simulated it using a 3D box potential.
- We have introduced the concept of Fermi energy: energy of the last occupied state.
- We have deduced the energy distribution of this electrons.

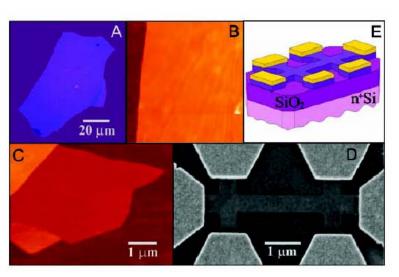
A 2D metal?

Consider graphite:



• Single layers obtained from exfoliation:





http://www.sciencemag.org/cgi/reprint/306/5696/666.pdf